

CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9 and 65,536 x 9 IDT7203 IDT7204 IDT7205 IDT7206 IDT7207 IDT7208

FEATURES:

- · First-In/First-Out Dual-Port memory
- 2,048 x 9 organization (IDT7203)
- 4,096 x 9 organization (IDT7204)
- 8,192 x 9 organization (IDT7205)
- 16,384 x 9 organization (IDT7206)
- 32.768 x 9 organization (IDT7207)
- 65,636 x 9 organization (IDT7208)
- · High-speed: 12ns access time
- Low power consumption
 - Active: 660mW (max.)
 - Power-down: 44mW (max.)
- · Asynchronous and simultaneous read and write
- · Fully expandable in both word depth and width
- Pin and functionally compatible with IDT720X family
- · Status Flags: Empty, Half-Full, Full
- · Retransmit capability
- High-performance CMOS technology
- · Military product compliant to MIL-STD-883, Class B
- Standard Military Drawing for #5962-88669 (IDT7203), 5962-89567 (IDT7203), and 5962-89568 (IDT7204) are listed on this function
- Industrial temperature range (-40°C to +85°C) is available (for plastic packages only)

DESCRIPTION:

DATA INPUTS

The IDT7203/7204/7205/7206/7207/7208 are dual-port memory buffers with internal pointers that load and empty data on a first-in/first-out basis. The device uses Full and Empty flags to prevent data overflow and underflow and expansion logic to allow for unlimited expansion capability in both word size and depth.

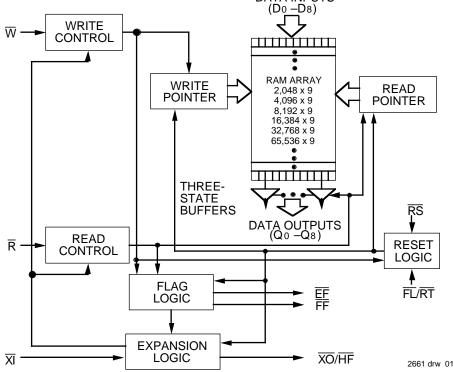
Data is toggled in and out of the device through the use of the Write (\overline{W}) and Read (\overline{R}) pins.

The device's 9-bit width provides a bit for a control or parity at the user's option. It also features a Retransmit (\overline{RT}) capability that allows the read pointer to be reset to its initial position when \overline{RT} is pulsed LOW. A Half-Full Flag is available in the single device and width expansion modes.

These FIFOs are fabricated using IDT's high-speed CMOS technology. They are designed for applications requiring asynchronous and simultaneous read/writes in multiprocessing, rate buffering and other applications.

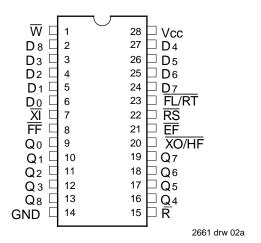
Military grade product is manufactured in compliance with the latest revision of MIL-STD-883, Class B.

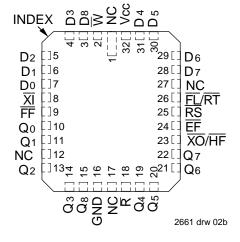
FUNCTIONAL BLOCK DIAGRAM



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PIN CONFIGURATIONS





TOP VIEW

TOP VIEW

Package Type	Reference Identifier	Order Code	Device Availability
PLASTIC DIP	P28-1	Р	All devices
PLASTIC THIN DIP	P28-2	TP	All except 7207/7208
CERDIP	D28-1	D	All except 7208
THIN CERDIP	D28-3	TD	Only for 7203/7204/7205
SOIC	SO28-3	so	Only for 7204

Package Type	Reference Identifier	Order Code	Device Availability
PLCC	J32-1	J	All devices
LCC ⁽¹⁾	L32-1	L	All except 7208

NOTES:

- 1. This package is only available in the military temperature range.
- 2. Consult factory for CERPACK pinout.

ABSOLUTE MAXIMUM RATINGS

Symbol	Rating	Com'l & Ind'l	Military	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
TSTG	Storage Temperature	-55 to + 125	-65 to +155	° C
IOUT	DC Output Current	-50 to +50	-50 to +50	mA

NOTE:

2661 tbl 01

 Stresses greater than those listed under ABSOLUTE MAXIMUM RAT-INGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
VCCM	Military Supply Voltage	4.5	5.0	5.5	V
VCCC	Commercial Supply Voltage	4.5	5.0	5.5	V
GND	Supply Voltage	0	0	0	٧
VIH ⁽¹⁾	Input High Voltage Commercial	2.0	1	_	٧
VIH ⁽¹⁾	Input High Voltage Military	2.2	_	_	V
VIL ⁽¹⁾	Input Low Voltage Commercial and Military	_	_	0.8	٧
ТА	Operating Temperature Commercial	0 to +70	_	_	°C
ТА	Operating Temperature Industrial	-40 to +85	_	_	°C
ТА	Operating Temperature Military	-55 to +125	_	_	°C

NOTE:

1. 1.5V undershoots are allowed for 10ns once per cycle.

2661 tbl 02

DC ELECTRICAL CHARACTERISTICS

(Commercial: $VCC = 5V \pm 10\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$; Industrial: $VCC = 5V \pm 10\%$, $TA = -40^{\circ}C$ to $+85^{\circ}C$; Military: $VCC = 5V \pm 10\%$, $TA = -55^{\circ}C$ to $+125^{\circ}C$)

		IDT7203 IDT7204 Commercial and Industrial ⁽¹⁾ tA = 12, 15, 20, 25, 35, 50 ns			IDT7203 IDT7204 Military ⁽²⁾ tA = 20, 30, 40, 50, 65, 80, 120 ns				
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	
ILI ⁽⁴⁾	Input Leakage Current (Any Input)	-1		1	-1	_	1	μΑ	
ILO ⁽⁵⁾	Output Leakage Current	-10	-	10	-10	_	10	μΑ	
Vон	Output Logic "1" Voltage IOH = -2mA	2.4		_	2.4	_	_	V	
Vol	Output Logic "0" Voltage IoL = 8mA	_	1	0.4	1	_	0.4	V	
ICC1 ^(6,7,8)	Active Power Supply Current	_		120	_	_	150	mA	
ICC2 ^(6,8,9)	Standby Current (R=W=RS=FL/RT=VIH)	_	_	12	_	_	25	mA	
ICC3 ^(6,8,9)	Power Down Current	_	_	2	_	_	4	mA	

			IDT7205 IDT7206 IDT7207 IDT7208 ^{(1,} cial and Ind 5, 20, 25, 35,	lustrial ⁽¹⁾	t.			
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
ILI ⁽⁴⁾	Input Leakage Current (Any Input)	-1	_	1	-1	_	1	μА
ILO ⁽⁵⁾	Output Leakage Current	-10	_	10	-10	_	10	μА
Vон	Output Logic "1" Voltage Iон = –2mA	2.4	_	_	2.4	_	_	٧
VOL	Output Logic "0" Voltage IoL = 8mA	_	_	0.4	_	_	0.4	V
ICC1 ^(6,7,8)	Active Power Supply Current	_	_	120	_	_	150	mA
ICC2 ^(6,8,9)	Standby Current (R=W=RS=FL/RT=VIH)	_	_	12	_	_	25	mA
ICC3 ^(6,8,9)	Power Down Current	_	_	8	_	_	12	mA

NOTES:

2661 tbl 03

- 1. Industrial temperature range product for the 25 ns speed grade is available as a standard device (excluding the 7208). All other speed grades are available by special order.
- 2. Speed grades of 65, 80, and 120 ns are only available in the ceramic DIP.
- 3. Only commercial speed grades of 20, 25 and 35 ns are available for the 7208.
- 4. Measurements with $0.4 \le VIN \le VCC$.
- 5. $\overline{R} \ge V_{IH}$, $0.4 \le V_{OUT} \le V_{CC}$.
- 6. Tested with outputs open (IOUT = 0).
- 7. RCLK and WCLK toggle at 20 MHz and data inputs switch at 10 MHz.
- 8. Icc measurements are made with outputs open.
- 9. All Inputs = Vcc 0.2V or GND + 0.2V, except RCLK and WCLK, which toggle at 20MHz.

AC TEST CONDITIONS

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	See Figure 1

2661 tbl 07

CAPACITANCE⁽¹⁾ (TA = +25°C, f = 1.0 MHz)

Symbol	Parameter	Condition	Max.	Unit
CIN ⁽¹⁾	Input Capacitance	VIN = 0V	10	pF
Cout ^(1,2)	Output Capacitance	Vout = 0V	10	pF

NOTES:

2661 tbl 08

- 1. This parameter is sampled and not 100% tested.
- 2. With output deselected.

AC ELECTRICAL CHARACTERISTICS(1)

(Commercial: $VCC = 5V \pm 10\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$; Industrial: $VCC = 5V \pm 10\%$, $TA = -40^{\circ}C$ to $+85^{\circ}C$; Military: $VCC = 5V \pm 10\%$, $TA = -55^{\circ}C$ to $+125^{\circ}C$)

			Com	mercia	al	Com'l	& Mil.	Com'l	& Ind'l ⁽²⁾	Mil	itary	Co	m'l	
		7203L12 7204L12		720 720 720	3L15 94L15 95L15 96L15 97L15	720 720 720	3L20 4L20 5L20 6L20 7L20	720 720 720	3L25 4L25 5L25 6L25 7L25	720 720 720	3L30 4L30 5L30 6L30 7L30	720 720 720	3L35 4L35 5L35 6L35 7L35	
									Comme	ercial				
						720	8L20	720	8L25			7208L35		
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fs	Shift Frequency	_	50	_	40	_	33.3	_	28.5	_	25	_	22.2	MHz
trc	Read Cycle Time	20	_	25	_	30	_	35		40	_	45	_	ns
tA	Access Time	_	12	_	15	_	20	_	25	_	30	_	35	ns
trr	Read Recovery Time	8	_	10	_	10	_	10	_	10	_	10	_	ns
trpw	Read Pulse Width ⁽³⁾	12	_	15	_	20	_	25	_	30	_	35	_	ns
trlz	Read LOW to Data Bus LOW(4)	3	_	5	_	5	_	5	_	5	_	5	_	ns
twLz	Write HIGH to Data Bus Low-Z ^(4,5)	3	_	5	_	5	_	5	_	5	_	10	_	ns
tDV	Data Valid from Read HIGH	5		5		5		5	_	5	_	5	_	ns
trhz	Read HIGH to Data Bus High-Z ⁽⁴⁾	_	12	_	15	_	15	_	18	_	20	_	20	ns
twc	Write Cycle Time	20		25		30		35	_	40		45		ns
twpw	Write Pulse Width ⁽³⁾	12		15		20		25		30		35		ns
twr	Write Recovery Time	8		10		10	_	10	_	10		10		ns
tDS	Data Set-up Time	9		11		12		15	_	18		18		ns
tDH	Data Hold Time	0		0		0		0		0		0		ns
trsc	Reset Cycle Time	20		25		30		35		40		45		ns
trs	Reset Pulse Width ⁽³⁾	12		15		20		25		30		35		ns
trss	Reset Set-up Time ⁽⁴⁾	12		15		20	_	25	_	30	_	35		ns
trtr	Reset Recovery Time	8		10		10		10	_	10		10		ns
trtc	Retransmit Cycle Time	20		25		30		35		40		45		ns
trt	Retransmit Pulse Width ⁽³⁾	12		15	_	20	_	25	_	30	_	35		ns
	Retransmit Set-up Time ⁽⁴⁾	12		15				25		30		35		
trop	'	8		10		20 10		10		10		10		ns
trsr	Retransmit Recovery Time Reset to EF LOW		<u> </u>		 25		30		35		<u> </u>		<u> </u>	ns
terL	Reset to HF and FF HIGH	_	17	_	25	_	30		35	_	40	_	45	ns
trtf	Retransmit LOW to Flags Valid		20		25		30		35		40		45	ns ns
tref	Read LOW to EF LOW		12		15		20		25		30		30	ns
tref	Read HIGH to FF HIGH		14		15		20		25		30		30	ns
tRPE	Read Pulse Width after EF HIGH	12		15	<u> 13</u>	20	_	25		30		35		ns
twef	Write HIGH to EF HIGH	_	12		15		20		25		30		30	ns
twr	Write LOW to FF LOW		14		15		20		25		30		30	ns
twrr	Write LOW to HF Flag LOW		17		25		30		35		40		45	ns
trhf	Read HIGH to HF Flag HIGH		17	_	25		30		35	_	40		45	ns
twpf	Write Pulse Width after FF HIGH	12		15		20	_	25		30	—	35	—,o	ns
txoL	Read/Write LOW to XO LOW	_	12		15	_	20		25	_	30	_	35	ns
txoh	Read/Write HIGH to XO HIGH		12		15	_	20		25	_	30		35	ns
txı	XI Pulse Width ⁽³⁾	12		15		20	_	25		30		35		ns
txir	XI Recovery Time	8		10		10	_	10		10		10		ns
txis	XI Set-up Time	8		10		10		10		10		15		ns
NOTES:	A Got-up Time			10		10		10		10		10		661 tbl 0

Timings referenced as in AC Test Conditions.
 Industrial temperature range product for the 25 ns speed grade is available as a standard device. All other speed grades are available by special order.

- 2661 tbl 05
 3. Pulse widths less than minimum are not allowed.
- 4. Values guaranteed by design, not currently tested.5. Only applies to read data flow-through mode.

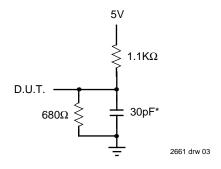
AC ELECTRICAL CHARACTERISTICS⁽¹⁾ (Continued)

(Commercial: $VCC = 5V \pm 10\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$; Military: $VCC = 5V \pm 10\%$, $TA = -55^{\circ}C$ to $+125^{\circ}C$)

		Mili	tary	Com'	& Mil.			Milit	ary ⁽²⁾			
		1	7203L40 7204L40		3L50 4L50 5L50 6L50 7L50		3L65 4L65		3L80 4L80		BL120 BL120	
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fs	Shift Frequency	_	20	_	15	_	12.5	_	10	-	7	MHz
trc	Read Cycle Time	50		65	_	80	_	100	_	140	_	ns
tA	Access Time	_	40	_	50	_	65	_	80	1	120	ns
trr	Read Recovery Time	10	_	15	_	15		20	_	20		ns
trpw	Read Pulse Width ⁽³⁾	40	_	50	_	65	_	80	_	120	_	ns
trlz	Read LOW to Data Bus LOW(4)	5	_	10	_	10	_	10	-	10	_	ns
twLz	Write HIGH to Data Bus Low-Z ^(4, 5)	10	_	15	_	15	_	20		20	_	ns
tDV	Data Valid from Read HIGH	5	_	5	_	5	_	5	_	5	_	ns
trhz	Read HIGH to Data Bus High-Z ⁽⁴⁾	_	25	_	30	_	30	_	30	_	35	ns
twc	Write Cycle Time	50	_	65	_	80	_	100	_	140	_	ns
twpw	Write Pulse Width ⁽³⁾	40	_	50	_	65	_	80	_	120	_	ns
twr	Write Recovery Time	10	_	15	_	15	_	20	_	20	_	ns
tDS	Data Set-up Time	20	_	30		30	_	40	_	40	_	ns
tDH	Data Hold Time	0	_	5	_	10	_	10	_	10		ns
trsc	Reset Cycle Time	50	_	65	_	80	_	100	_	140	_	ns
trs	Reset Pulse Width ⁽³⁾	40	_	50	_	65	_	80	_	120	_	ns
trss	Reset Set-up Time ⁽⁴⁾	40	_	50	_	65	_	80	_	120	_	ns
trsr	Reset Recovery Time	10	_	15	_	15	_	20	_	20	_	ns
trtc	Retransmit Cycle Time	50	_	65	_	80	_	100	_	140	_	ns
trt	Retransmit Pulse Width ⁽³⁾	40	_	50	_	65	_	80	_	120	_	ns
trts	Retransmit Set-up Time ⁽⁴⁾	40	_	50		65	_	80	_	120	_	ns
trsr	Retransmit Recovery Time	10		15		15		20	_	20		ns
tEFL	Reset to EF LOW	_	50	_	65	_	80	_	100		140	ns
thfh, tffh	Reset to HF and FF HIGH	_	50	_	65	_	80	_	100	_	140	ns
trtf	Retransmit LOW to Flags Valid	_	50	_	65	_	80	_	100	_	140	ns
tref	Read LOW to EF Flag LOW	_	35	_	45	_	60	_	60	_	60	ns
trff	Read HIGH to FF HIGH	_	35	_	45	_	60	_	60		60	ns
trpe	Read Pulse Width after EF HIGH	40	_	50	_	65	_	80	_	120	_	ns
tweF	Write HIGH to EF HIGH	_	35	_	45	_	60	_	60	_	60	ns
twff	Write LOW to FF LOW	_	35	_	45	_	60	_	60	-	60	ns
twhF	Write LOW to HF LOW	_	50	_	65	_	80	_	100		140	ns
trhf	Read HIGH to HF HIGH	_	50	_	65	_	80	_	100	-	140	ns
twpf	Write Pulse Width after FF HIGH	40	_	50	_	65	_	80	_	120	_	ns
txoL	Read/Write LOW to XO LOW	<u> </u>	40	_	50	_	65	_	80	_	120	ns
txoн	Read/Write HIGH to XO HIGH	_	40	_	50	_	65	_	80	_	120	ns
txı	XI Pulse Width ⁽³⁾	40	_	50	_	65	_	80	_	120	_	ns
txir	XI Recovery Time	10	_	10	_	10	_	10	_	10	_	ns
txis	XI Set-up Time	15	_	15	_	15	_	15	_	15	_	ns

- Timings referenced as in AC Test Conditions.
 Speed grades 65, 80, and 120ns are only available in the CERDIP package.
 Pulse widths less than minimum are not allowed.
- 4. Values guaranteed by design, not currently tested.5. Only applies to read data flow-through mode.

2661 tbl 06



OR EQUIVALENT CIRCUIT

Figure 1. Output Load

*Includes jig and scope capacitances.

SIGNAL DESCRIPTIONS

Inputs:

DATA IN (D0–D8) — Data inputs for 9-bit wide data.

Controls:

RESET (\overline{RS}) — Reset is accomplished whenever the Reset (\overline{RS}) input is taken to a LOW state. During reset, both internal read and write pointers are set to the first location. A reset is required after power-up before a write operation can take place. Both the Read Enable (\overline{R}) and Write Enable (\overline{W}) inputs must be in the HIGH state during the window shown in Figure 2 (i.e. trss before the rising edge of \overline{RS}) and should not change until trsr after the rising edge of \overline{RS} .

WRITE ENABLE (\overline{W}) —A write cycle is initiated on the falling edge of this input if the Full Flag (\overline{FF}) is not set. Data set-up and hold times must be adhered-to, with respect to the rising edge of the Write Enable (\overline{W}). Data is stored in the RAM array sequentially and independently of any on-going read operation.

After half of the memory is filled, and at the falling edge of the next write operation, the Half-Full Flag (\overline{HF}) will be set to LOW, and will remain set until the difference between the write pointer and read pointer is less-than or equal to one-half of the total memory of the device. The Half-Full Flag (\overline{HF}) is then reset by the rising edge of the read operation.

To prevent data overflow, the Full Flag (\overline{FF}) will go LOW on the falling edge of the last write signal, which inhibits further write operations. Upon the completion of a valid read operation, the Full Flag (\overline{FF}) will go HIGH after treff, allowing a new valid write to begin. When the FIFO is full, the internal write pointer is blocked from \overline{W} , so external changes in \overline{W} will not affect the FIFO when it is full.

READ ENABLE (\overline{R}) — A read cycle is initiated on the falling edge of the Read Enable (\overline{R}) , provided the Empty Flag (\overline{EF}) is not set. The data is accessed on a First-In/First-Out basis, independent of any ongoing write operations. After Read Enable (\overline{R}) goes HIGH, the Data Outputs (Q0 through Q8) will return to a high-impedance condition until the next Read operation. When all the data has been read from the FIFO, the Empty Flag (\overline{EF}) will go

LOW, allowing the "final" read cycle but inhibiting further read operations, with the data outputs remaining in a high-impedance state. Once a valid write operation has been accomplished, the Empty Flag ($\overline{\text{EF}}$) will go HIGH after twef and a valid Read can then begin. When the FIFO is empty, the internal read pointer is blocked from \overline{R} so external changes will not affect the FIFO when it is empty.

FIRST LOAD/RETRANSMIT (FL/RT) — This is a dual-purpose input. In the Depth Expansion Mode, this pin is grounded to indicate that it is the first device loaded (see Operating Modes). The Single Device Mode is initiated by grounding the Expansion In (\overline{XI}) .

The IDT7203/7204/7205/7206/7207/7208 can be made to retransmit data when the Retransmit Enable Control (\overline{RT}) input is pulsed LOW. A retransmit operation will set the internal read pointer to the first location and will not affect the write pointer. The status of the Flags will change depending on the relative locations of the read and write pointers. Read Enable (\overline{R}) and Write Enable (\overline{W}) must be in the HIGH state during retransmit. This feature is useful when less than 2,048/4,096/8,192/16,384/32,768/65,536 writes are performed between resets. The retransmit feature is not compatible with the Depth Expansion Mode.

EXPANSION IN (\overline{XI} **)** — This input is a dual-purpose pin. Expansion In (\overline{XI}) is grounded to indicate an operation in the single device mode. Expansion In (\overline{XI}) is connected to Expansion Out (\overline{XO}) of the previous device in the Depth Expansion or Daisy-Chain Mode.

Outputs:

FULL FLAG (FF) — The Full Flag (FF) will go LOW, inhibiting further write operations, when the device is full. If the read pointer is not moved after Reset (\overline{RS}), the Full Flag (\overline{FF}) will go LOW after 2,048/4,096/8,192/16,384/32,768/65,536 writes.

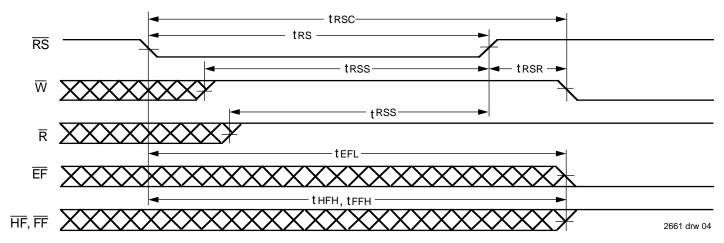
EMPTY FLAG (\overline{\text{EF}}) — The Empty Flag ($\overline{\text{EF}}$) will go LOW, inhibiting further read operations, when the read pointer is equal to the write pointer, indicating that the device is empty.

EXPANSION OUT/HALF-FULL FLAG (\overline{XO/HF}) — This is a dual-purpose output. In the single device mode, when Expansion In (\overline{XI}) is grounded, this output acts as an indication of a half-full memory.

After half of the memory is filled, and at the falling edge of the next write operation, the Half-Full Flag (HF) will be set to LOW and will remain set until the difference between the write pointer and read pointer is less than or equal to one half of the total memory of the device. The Half-Full Flag (HF) is then reset by the rising edge of the read operation.

In the Depth Expansion Mode, Expansion In (\overline{XI}) is connected to Expansion Out (\overline{XO}) of the previous device. This output acts as a signal to the next device in the Daisy Chain by providing a pulse to the next device when the previous device reaches the last location of memory. There will be an \overline{XO} pulse when the Write pointer reaches the last location of memory, and an additional \overline{XO} pulse when the Read pointer reaches the last location of memory.

DATA OUTPUTS (Q0-Q8) — Q0-Q8 are data outputs for 9-bit wide data. These outputs are in a high-impedance condition whenever Read (\overline{R}) is in a HIGH state.



NOTE:

1. \overline{W} and $\overline{R} = V H$ around the rising edge of \overline{RS} .

Figure 2. Reset

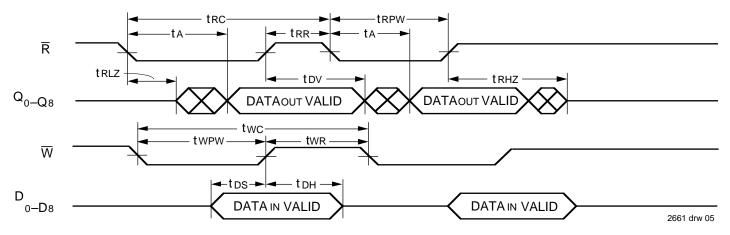


Figure 3. Asynchronous Write and Read Operation

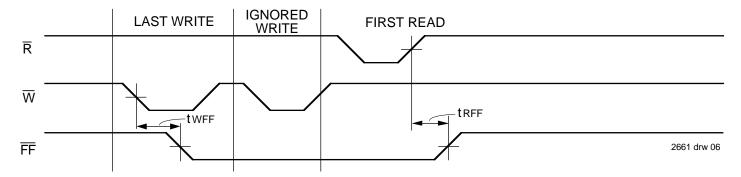


Figure 4. Full FlagTiming From Last Write to First Read

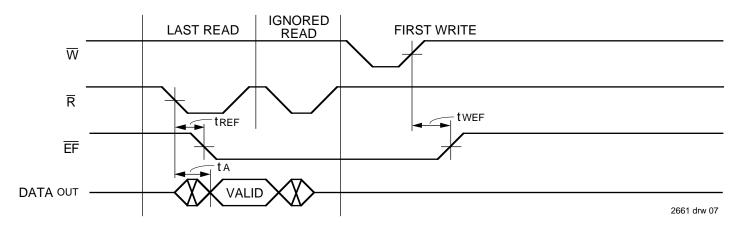
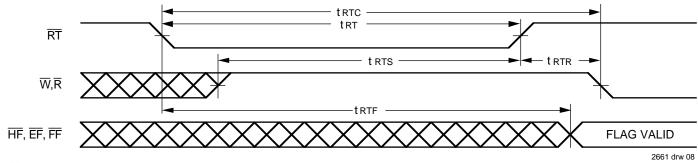


Figure 5. Empty Flag Timing From Last Read to First Write



NOTE:

1. $\overline{\text{EF}}$, $\overline{\text{FF}}$ and $\overline{\text{HF}}$ may change status during Retransmit, but flags will be valid at trtc.

Figure 6. Retransmit

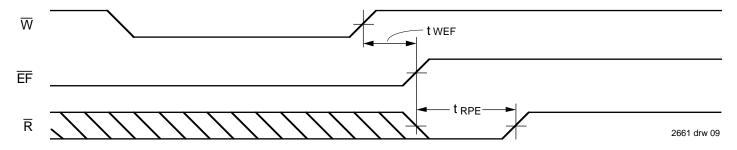


Figure 7. Minimum Timing for an Empty Flag Coincident Read Pulse.

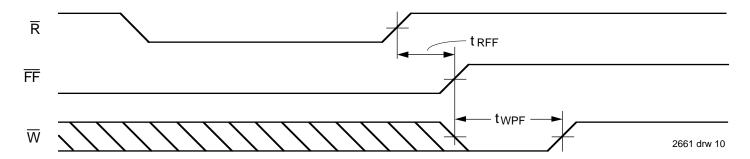


Figure 8. Minimum Timing for a Full Flag Coincident Write Pulse.

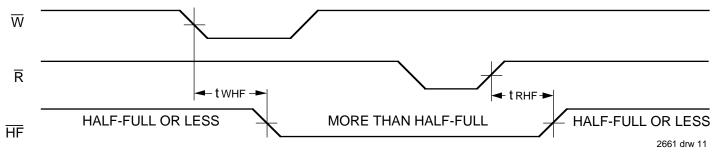


Figure 9. Half-Full Flag Timing

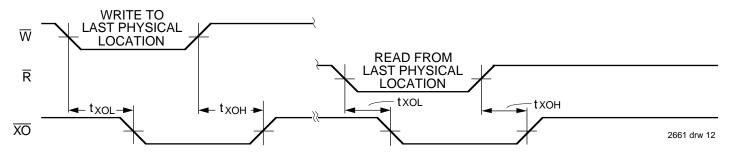


Figure 10. Expansion Out

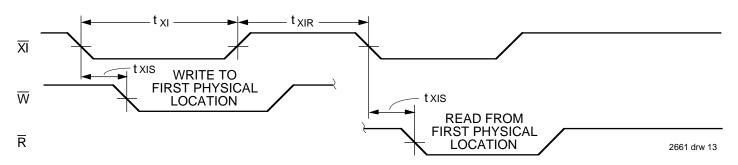


Figure 11. Expansion In

OPERATING MODES:

Care must be taken to assure that the appropriate flag is monitored by each system (i.e. \overline{FF} is monitored on the device where \overline{W} is used; \overline{EF} is monitored on the device where \overline{R} is used). For additional information on the IDT7203/7204/7205/7206/7207, refer to Tech Note 8: Operating FIFOs on Full and Empty Boundary Conditions and Tech Note 6: Designing with FIFOs.

Single Device Mode

A single IDT7203/7204/7205/7206/7207/7208 may be used when the application requirements are for 2,048/4,096/8,192/16,384/32,768/65,536 words or less. These FIFOs are in a Single Device Configuration when the Expansion In (\overline{XI}) control input is grounded (see Figure 12).

Depth Expansion

These FIFOs can easily be adapted to applications when the requirements are for greater than 2,048/4,096/8,192/ 16,384/32,768/65,536 words. Figure 14 demonstrates Depth Expansion using three IDT7203/7204/7205/7206/7207/7208s. Any depth can be attained by adding additional IDT7203/7204/7205/7206/7207/7208s. These devices operate in the Depth Expansion mode when the following conditions are met:

- 1. The first device must be designated by grounding the First Load (FL) control input.
- 2. All other devices must have FL in the HIGH state.
- 3. The Expansion Out (\overline{XO}) pin of each device must be tied to the Expansion In (\overline{XI}) pin of the next device. See Figure 14.
- 4. External logic is needed to generate a composite Full Flag (FF) and Empty Flag (EF). This requires the ORing of all EFs and ORing of all FFs (i.e. all must be set to generate the correct composite FF or EF). See Figure 14.
- 5. The Retransmit (RT) function and Half-Full Flag (HF) are not available in the Depth Expansion Mode.

For additional information on the IDT7203/7204/7205/7206/7207, refer to Tech Note 9: *Cascading FIFOs or FIFO Modules*.

USAGE MODES:

Width Expansion

Word width may be increased simply by connecting the corresponding input control signals of multiple devices. Status flags ($\overline{\text{EF}}$, $\overline{\text{FF}}$ and $\overline{\text{HF}}$) can be detected from any one device. Figure 13 demonstrates an 18-bit word width by using two IDT7203/7204/7205/7206/7207/7208s. Any word width can be attained by adding additional IDT7203/7204/7205/7206/7207/7208s (Figure 13).

Bidirectional Operation

Applications which require data buffering between two systems (each system capable of Read and Write operations) can be achieved by pairing IDT7203/7204/7205/7206/7207/7208s as shown in Figure 16. Both Depth Expansion and Width Expansion may be used in this mode.

Data Flow-Through

Two types of flow-through modes are permitted, a read flow-through and write flow-through mode. For the read flow-

through mode (Figure 17), the FIFO permits a reading of a single word after writing one word of data into an empty FIFO. The data is enabled on the bus in (tWEF + tA) ns after the rising edge of \overline{W} , called the first write edge, and it remains on the bus until the \overline{R} line is raised from LOW-to-HIGH, after which the bus would go into a three-state mode after tRHZ ns. The \overline{EF} line would have a pulse showing temporary deassertion and then would be asserted.

In the write flow-through mode (Figure 18), the FIFO permits the writing of a single word of data immediately after reading one word of data from a full FIFO. The \overline{R} line causes the \overline{FF} to be deasserted but the \overline{W} line being LOW causes it to be asserted again in anticipation of a new data word. On the rising edge of \overline{W} , the new word is loaded in the FIFO. The \overline{W} line must be toggled when \overline{FF} is not asserted to write new data in the FIFO and to increment the write pointer.

Compound Expansion

The two expansion techniques described above can be applied together in a straightforward manner to achieve large FIFO arrays (see Figure 15).

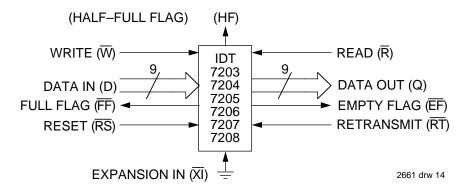
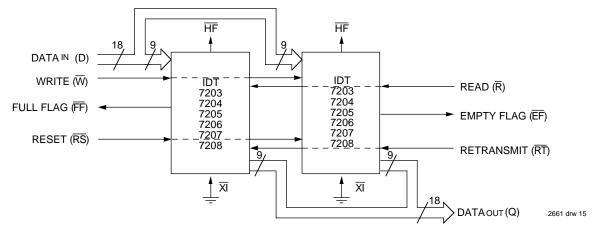


Figure 12. Block Diagram of 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9, 65,536 x 9 FIFO Used in Single Device Mode



NOTE:

Flag detection is accomplished by monitoring the FF, EF and HF signals on either (any) device used in the width expansion configuration.
Do not connect any output signals together.

Figure 13. Block Diagram of 2,048 x 18, 4,096 x 18, 8,192 x 18, 16,384 x 18, 32,768 x 18, 65,536 x 18 FIFO Memory Used in Width Expansion Mode

TRUTH TABLES

TABLE I – RESET AND RETRANSMIT

SINGLE DEVICE CONFIGURATION/WIDTH EXPANSION MODE

		Inputs		Internal	Status	Outputs			
Mode	RS	RT	ΧĪ	Read Pointer	Write Pointer	ĒĒ	FF	HF	
Reset	0	Х	0	Location Zero	Location Zero	0	1	1	
Retransmit	1	0	0	Location Zero	Unchanged	Х	Х	Х	
Read/Write	1	1	0	Increment (1)	Increment ⁽¹⁾	Х	Х	Х	

NOTE:

1. Pointer will Increment if flag is HIGH.

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TABLE II - RESET AND FIRST LOAD

DEPTH EXPANSION/COMPOUND EXPANSION MODE

	Inputs			Interna	l Status	Out	puts
Mode	RS	FL	XI	Read Pointer	Write Pointer	ĒĒ	FF
Reset First Device	0	0	(1)	Location Zero	Location Zero	0	1
Reset all Other Devices	0	1	(1)	Location Zero	Location Zero	0	1
Read/Write	1	Х	(1)	Х	Х	Х	Х

NOTES:

1. $\overline{\overline{XI}}$ is connected to $\overline{\overline{XO}}$ of previous device. See Figure 14.

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2. RS = Reset Input, FL/RT = First Load/Retransmit, F = Empty Flag Output, FF = Full Flag Output, XI = Expansion Input, HF = Half-Full Flag Output

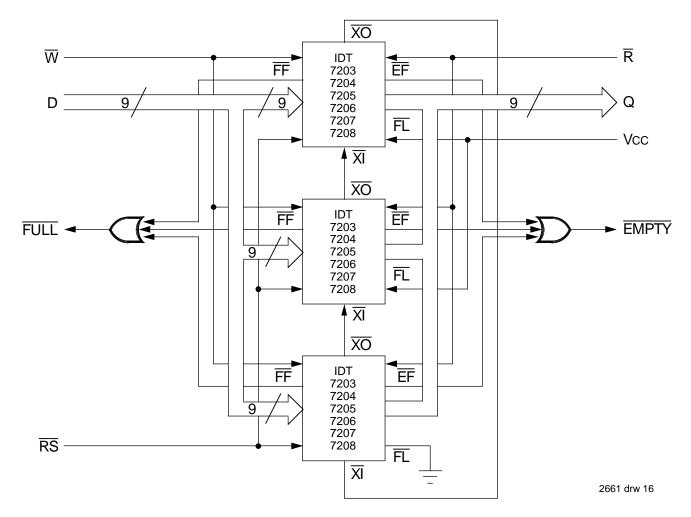
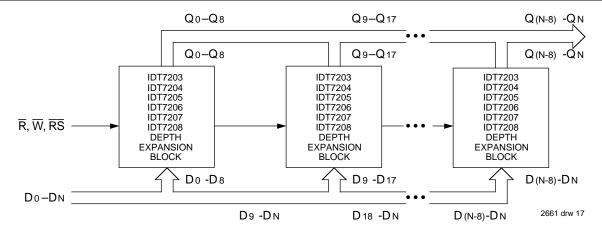


Figure 14. Block Diagram of 6,144 x 9, 12,288 x 9, 24,576 x 9, 49,152 x 9, 98,304 x 9, 196,608 x 9 FIFO Memory (Depth Expansion)



NOTES:

- 1. For depth expansion block see section on Depth Expansion and Figure 14.
- 2. For Flag detection see section on Width Expansion and Figure 13.

Figure 15. Compound FIFO Expansion

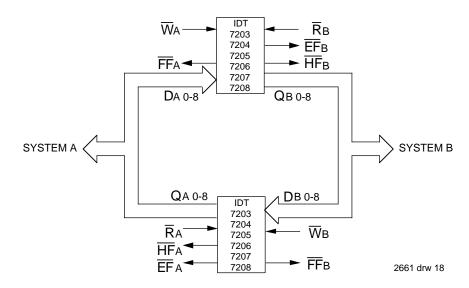


Figure 16. Bidirectional FIFO Operation

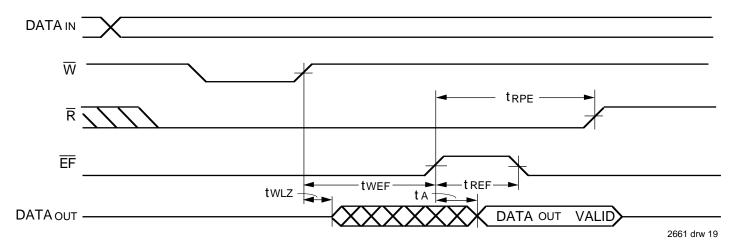


Figure 17. Read Data Flow-Through Mode

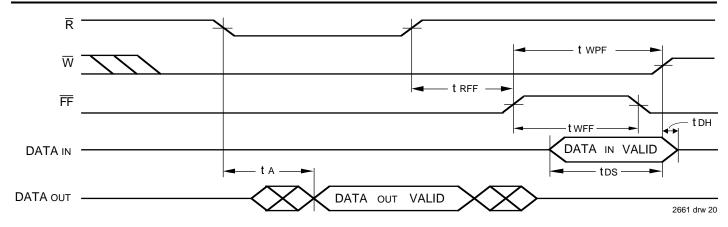
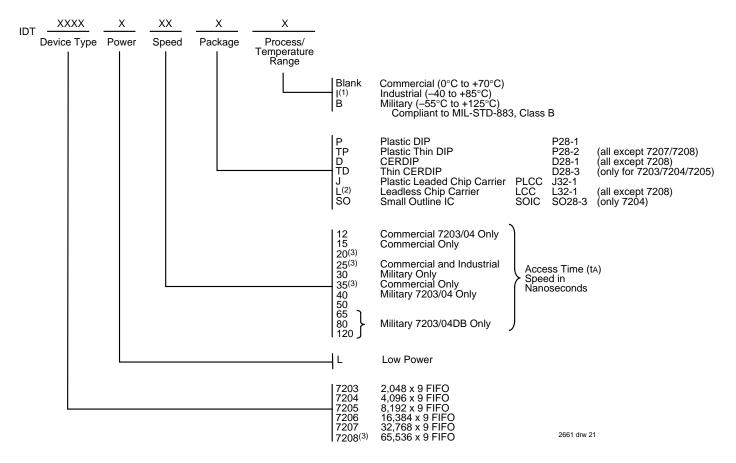


Figure 18. Write Data Flow-Through Mode

ORDERING INFORMATION



NOTES:

- 1. Industrial temperature range is available for plastic packages by special order for speed grades faster than 25 ns (excluding the 7208).
- 2. The LCC is only available in the military temperature range.
- 3. The 7208 is only available in commercial speed grades of 20, 25 and 35 ns.